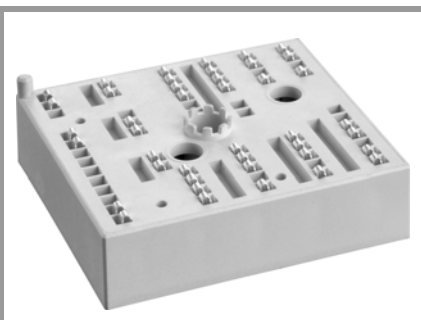


SKiIP 28MLI07E3V1



MiniSKiIP® 2

3-Level NPC Inverter

SKiIP 28MLI07E3V1

Features

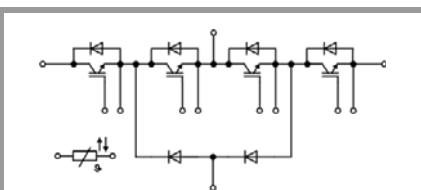
- 650V Trench IGBTs
- Robust and soft diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

Typical Applications*

- Uninterruptible power supplies (UPS)
- Solar inverters

Remarks

- Case temperature limited to $T_C = 125^\circ\text{C}$ max.; $T_C = T_S$ (valid for baseplateless modules)
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{op} = -40 \dots +150^\circ\text{C}$)



MLI

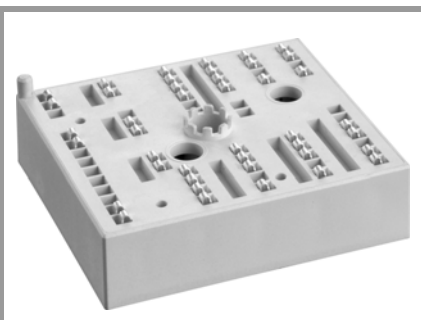
Absolute Maximum Ratings

| Symbol | Conditions | Values | Unit | |
|-----------------------|---|---------------------------|------------------|---------------|
| IGBT | | | | |
| V_{CES} | | 650 | V | |
| I_C | $T_j = 175^\circ\text{C}$ | $T_s = 25^\circ\text{C}$ | 135 | A |
| | | $T_s = 70^\circ\text{C}$ | 107 | A |
| I_{Cnom} | | 150 | A | |
| I_{CRM} | $I_{CRM} = 2 \times I_{Cnom}$ | 300 | A | |
| V_{GES} | | -20 ... 20 | V | |
| t_{psc} | $V_{CC} = 360\text{ V}$ $V_{GE} \leq 15\text{ V}$ $V_{CES} \leq 650\text{ V}$ | $T_j = 150^\circ\text{C}$ | 6 | μs |
| | | | | |
| T_j | | -40 ... 175 | $^\circ\text{C}$ | |
| Inverse diode | | | | |
| I_F | $T_j = 175^\circ\text{C}$ | $T_s = 25^\circ\text{C}$ | 126 | A |
| | | $T_s = 70^\circ\text{C}$ | 97 | A |
| I_{Fnom} | | 150 | A | |
| I_{FRM} | $I_{FRM} = 2 \times I_{Fnom}$ | 300 | A | |
| I_{FSM} | $t_p = 10\text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$ | 1200 | A | |
| T_j | | -40 ... 175 | $^\circ\text{C}$ | |
| Clamping diode | | | | |
| I_F | $T_j = 175^\circ\text{C}$ | $T_s = 25^\circ\text{C}$ | 126 | A |
| | | $T_s = 70^\circ\text{C}$ | 97 | A |
| I_{Fnom} | | 150 | A | |
| I_{FRM} | $I_{FRM} = 2 \times I_{Fnom}$ | 300 | A | |
| I_{FSM} | $10\text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$ | 1200 | A | |
| T_j | | -40 ... 175 | $^\circ\text{C}$ | |
| Module | | | | |
| $I_{t(RMS)}$ | $T_{terminal} = 80^\circ\text{C}, 20\text{ A per spring}$ | 120 | A | |
| T_{stg} | | -40 ... 125 | $^\circ\text{C}$ | |
| V_{isol} | AC sinus 50 Hz, $t = 1\text{ min}$ | 2500 | V | |

Characteristics

| Symbol | Conditions | min. | typ. | max. | Unit |
|---------------|---|---------------------------|------|------|------------------|
| IGBT | | | | | |
| $V_{CE(sat)}$ | $I_C = 150\text{ A}$ $V_{GE} = 15\text{ V}$ chiplevel | $T_j = 25^\circ\text{C}$ | 1.45 | 1.90 | V |
| | | $T_j = 150^\circ\text{C}$ | 1.70 | 2.10 | V |
| V_{CE0} | chiplevel | $T_j = 25^\circ\text{C}$ | 0.9 | 1 | V |
| | | $T_j = 150^\circ\text{C}$ | 0.82 | 0.9 | V |
| r_{CE} | $V_{GE} = 15\text{ V}$ chiplevel | $T_j = 25^\circ\text{C}$ | 3.7 | 6.0 | $\text{m}\Omega$ |
| | | $T_j = 150^\circ\text{C}$ | 5.9 | 8.0 | $\text{m}\Omega$ |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}, I_C = 2.4\text{ mA}$ | 5.1 | 5.8 | 6.4 | V |
| I_{CES} | $V_{GE} = 0\text{ V}$ $V_{CE} = 650\text{ V}$ | $T_j = 25^\circ\text{C}$ | 0.1 | 0.3 | mA |
| | | | | | mA |
| C_{ies} | $V_{CE} = 25\text{ V}$ | | 9.24 | | nF |
| C_{oes} | $V_{GE} = 0\text{ V}$ | | 0.58 | | nF |
| C_{res} | | | 0.27 | | nF |
| Q_G | $V_{GE} = -8\text{ V} \dots +15\text{ V}$ | | 1200 | | nC |
| R_{Gint} | $T_j = 25^\circ\text{C}$ | | 2.00 | | Ω |

SKiIP 28MLI07E3V1



MiniSKiIP® 2

3-Level NPC Inverter

SKiIP 28MLI07E3V1

Features

- 650V Trench IGBTs
- Robust and soft diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

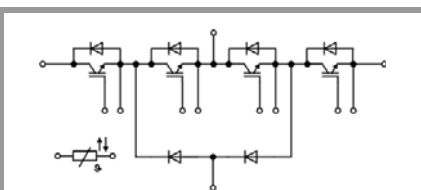
Typical Applications*

- Uninterruptible power supplies (UPS)
- Solar inverters

Remarks

- Case temperature limited to $T_C = 125^\circ\text{C}$ max.; $T_C = T_S$ (valid for baseplateless modules)
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{op} = -40 \dots +150^\circ\text{C}$)

| Characteristics | | | | | | |
|---------------------------|---|---------------------------|------|--------------|-------|---------------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| T1 / T4 | | | | | | |
| $t_{d(on)}$ | $V_{CE} = 300\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 108 | | ns |
| t_r | $I_C = 150\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 73 | | ns |
| E_{on} | $V_{GE} = +15/-15\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 5.5 | | mJ |
| $t_{d(off)}$ | $R_{G\ on} = 3\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 268 | | ns |
| t_f | $R_{G\ off} = 1.6\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 76 | | ns |
| E_{off} | $di/dt_{on} = 2100\text{ A}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 5.6 | | mJ |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste} = 0.8\text{ W}/\text{K}\cdot\text{m}$ | | | 0.55 | | K/W |
| T2 / T3 | | | | | | |
| $t_{d(on)}$ | $V_{CE} = 300\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 106 | | ns |
| t_r | $I_C = 150\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 64 | | ns |
| E_{on} | $V_{GE} = +15/-15\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 2 | | mJ |
| $t_{d(off)}$ | $R_{G\ on} = 3\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 268 | | ns |
| t_f | $R_{G\ off} = 1.6\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 77 | | ns |
| E_{off} | $di/dt_{on} = 2520\text{ A}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 5.2 | | mJ |
| $R_{th(j-s)}$ | | | | 0.55 | | K/W |
| Inverse diode | | | | | | |
| $V_F = V_{EC}$ | $I_F = 150\text{ A}$ | $T_j = 25^\circ\text{C}$ | | 1.4 | 1.8 | V |
| | $V_{GE} = 0\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 1.4 | 1.8 | V |
| | chipelevel | | | | | |
| V_{F0} | chipelevel | $T_j = 25^\circ\text{C}$ | | 1.04 | 1.236 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.85 | 0.99 | V |
| r_F | chipelevel | $T_j = 25^\circ\text{C}$ | | 2.4 | 3.5 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 3.6 | 5.2 | m Ω |
| I_{RRM} | $I_F = 150\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 121 | | A |
| Q_{rr} | $di/dt_{off} = 2450\text{ A}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 20 | | μC |
| E_{rr} | $V_{GE} = -15\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 5.5 | | mJ |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste} = 0.8\text{ W}/\text{K}\cdot\text{m}$ | | | 0.75 | | K/W |
| Clamping diode | | | | | | |
| $V_F = V_{EC}$ | $I_F = 150\text{ A}$ | $T_j = 25^\circ\text{C}$ | | 1.4 | 1.8 | V |
| | $V_{GE} = 0\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 1.4 | 1.8 | V |
| | chipelevel | | | | | |
| V_{F0} | chipelevel | $T_j = 25^\circ\text{C}$ | | 1.04 | 1.236 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.85 | 0.99 | V |
| r_F | chipelevel | $T_j = 25^\circ\text{C}$ | | 2.4 | 3.5 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 3.6 | 5.2 | m Ω |
| I_{RRM} | $I_F = 150\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 116 | | A |
| Q_{rr} | $di/dt_{off} = 2210\text{ A}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 13.2 | | μC |
| E_{rr} | $V_{GE} = -15\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 2.6 | | mJ |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste} = 0.8\text{ W}/\text{K}\cdot\text{m}$ | | | 0.75 | | K/W |
| Module | | | | | | |
| M_s | to heat sink | | 2 | | 2.5 | Nm |
| w | weight | | | 55 | | g |
| Temperature Sensor | | | | | | |
| R_{25} | NTC, $T_r = 25^\circ\text{C}^1)$ | | | 5.0 \pm 5% | | k Ω |



MLI

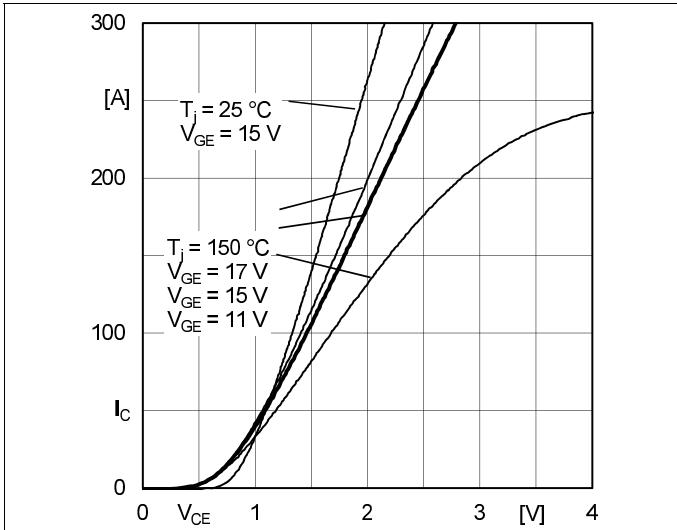


Fig. 1: Typ. output characteristic, inclusive R_{CC+EE}

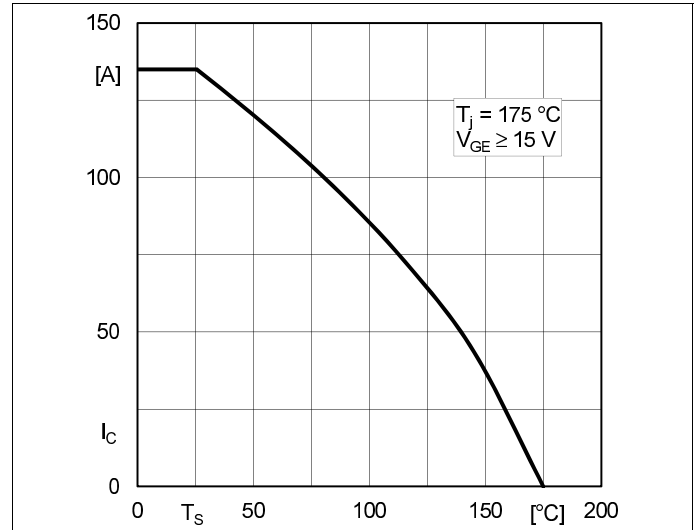


Fig. 2: Rated current vs. temperature $I_C = f(T_s)$

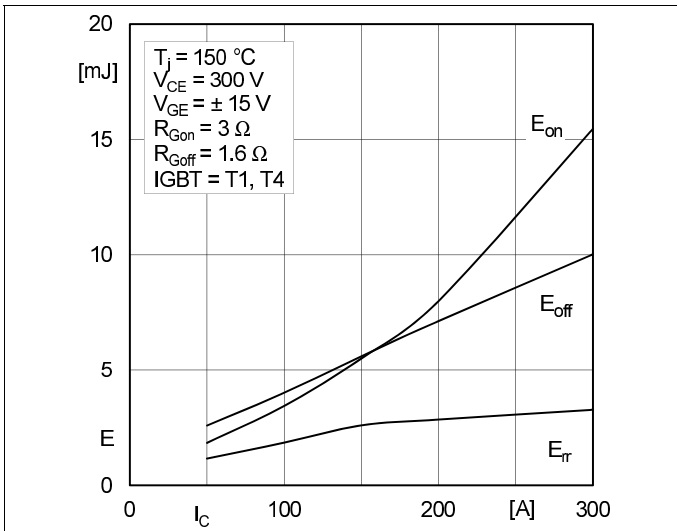


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

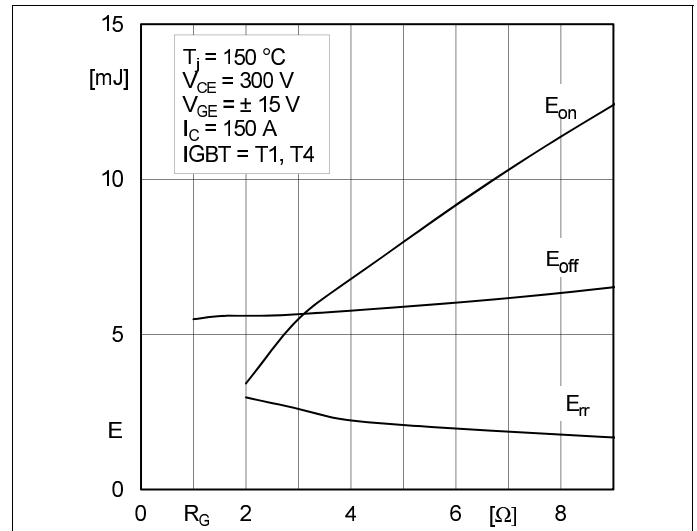


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

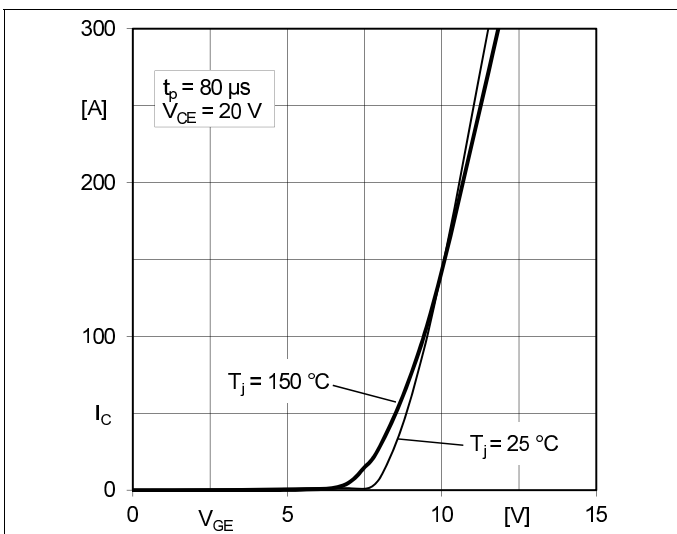


Fig. 5: Typ. transfer characteristic

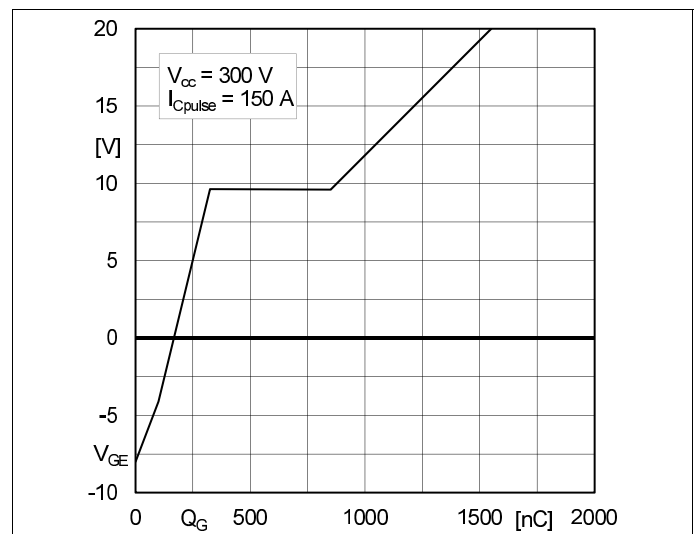
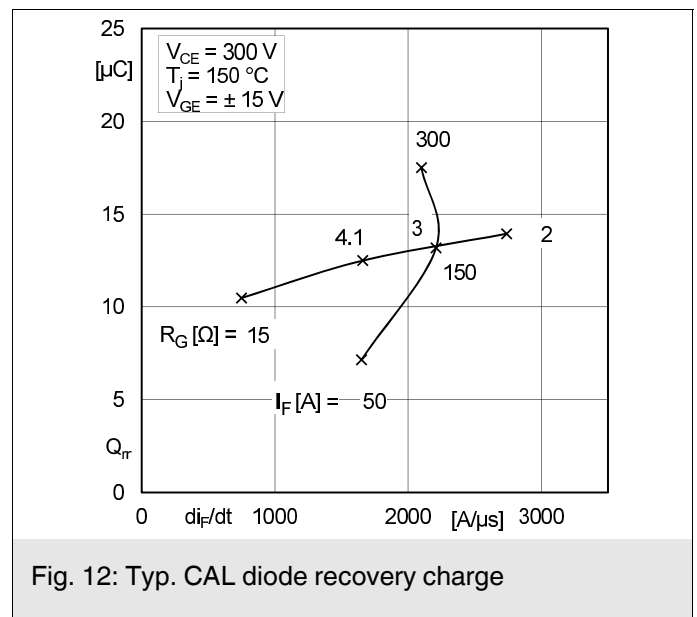
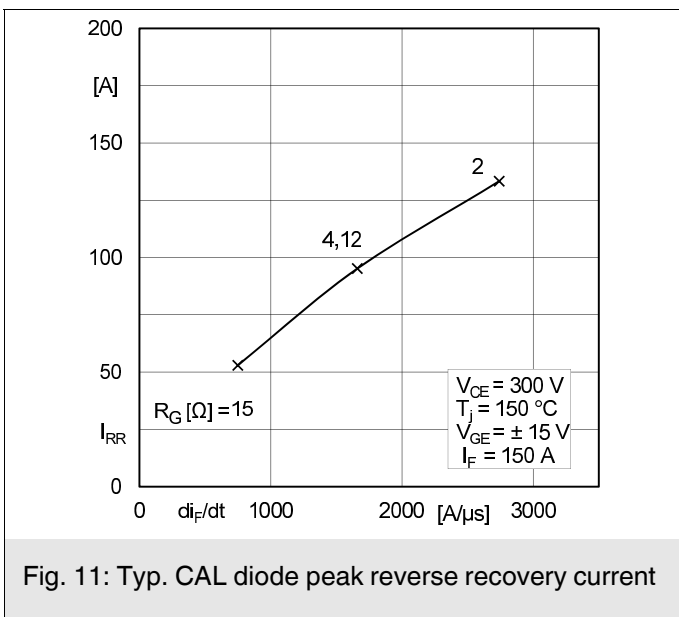
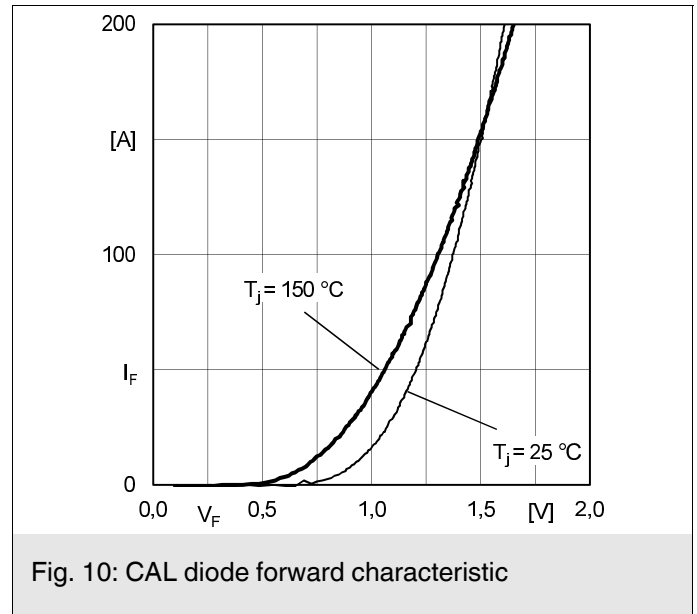
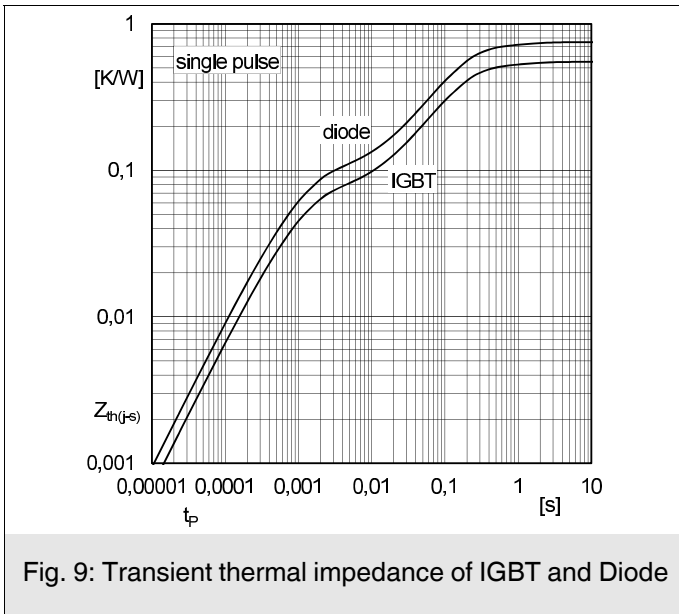
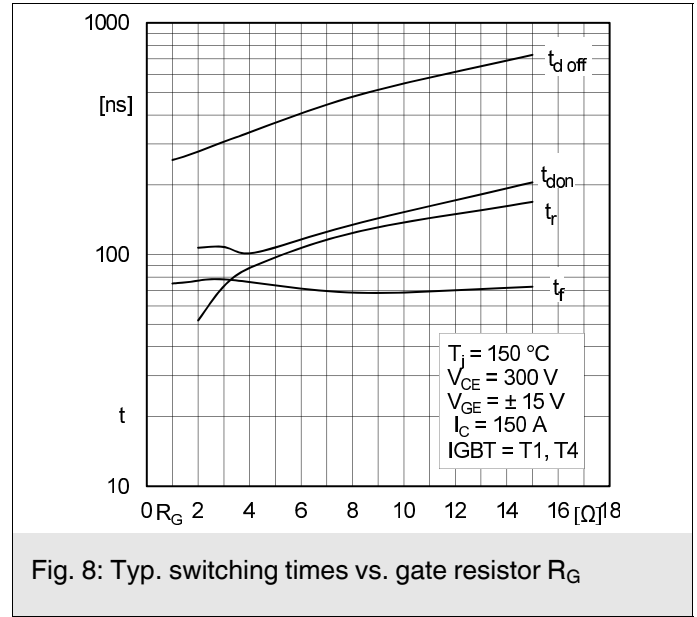
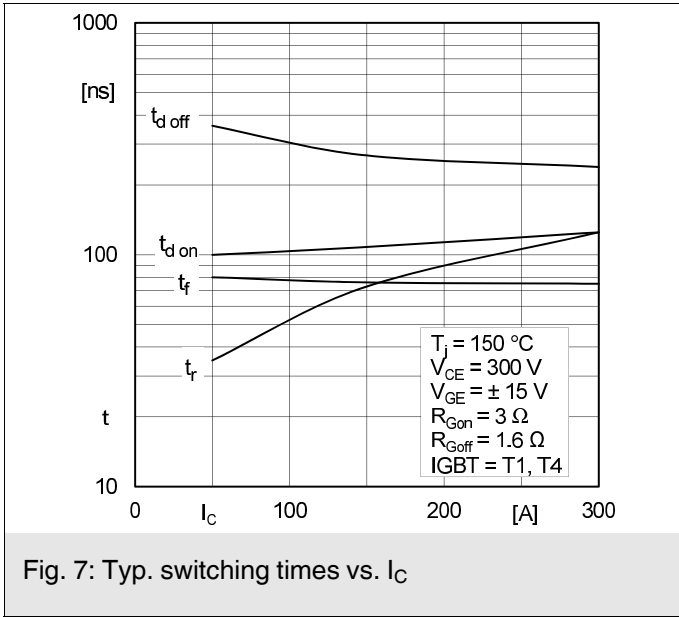
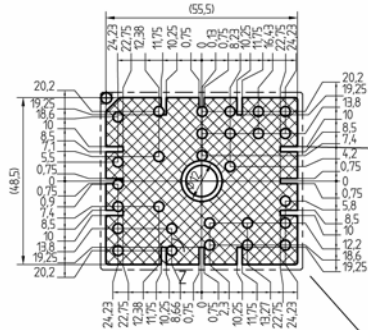


Fig. 6: Typ. gate charge characteristic



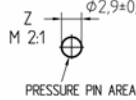
PCB PCB TOP-VIEW



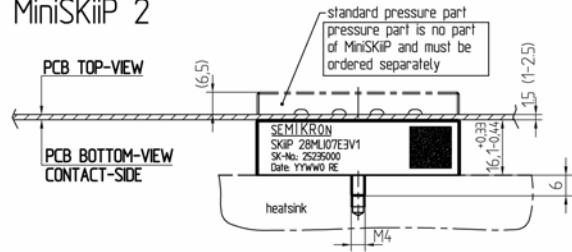
Only for the standard pressure part:
Accessible for mounting of SMD (max height 3.5) on PCB by customer

mounting area

Tolerances of pressure part dimensions ISO 2768-m

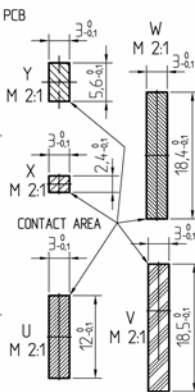
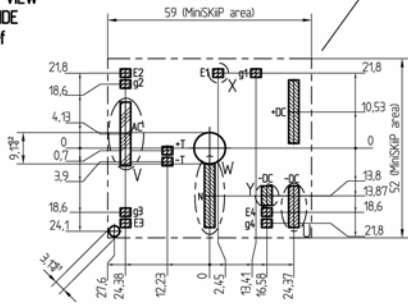


MiniSKiIP 2

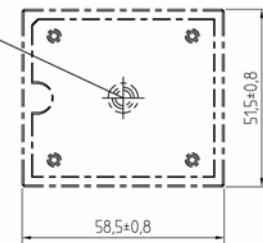


PCB TOP-VIEW PCB BOTTOM-VIEW CONTACT-SIDE

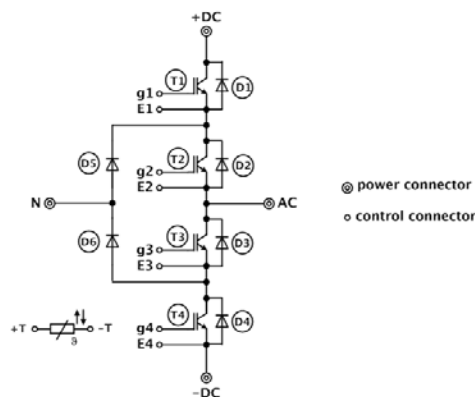
PCB BOTTOM-VIEW CONTACT-SIDE ISO 2768-f



For mounting please follow the assembly instruction



pinout, dimensions



pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.